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Super Fast Surface Mount Rectifiers Reverse Voltage 200V to 1600V Forward Current 1.5A

YG10D thru YG10Y

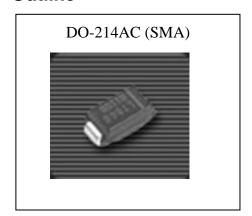
Features

- For surface mounted application
- Low profile package
- Built-in stain relief, ideal for automatic placement
- Easy pick and place
- Glass passivated junction chip
- High temperature soldering: 250°C/10 seconds at terminals
- Plastic material used carries UL flammability classification 94V-0

Mechanical Data

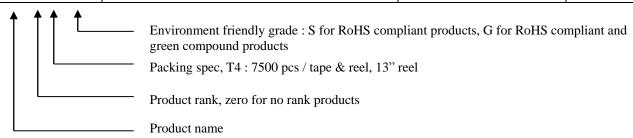
- Case: SMA/DO-214AC molded plastic
- Terminals: Pure tin plated, solderable per MIL-STD-750 method 2026
- Polarity: Indicated by cathode bandWeight: 0.064 gram, 0.002 ounce

Outline



Ordering Information

Device	Package	Shipping	Marking
YG10D-0-T4-G	CMA	7500 pcs / Tape & Reel	YG10D
YG10G-0-T4-G			YG10G
YG10J-0-T4-G	SMA (Pb-free lead plating and halogen-free		YG10J
YG10K-0-T4-G	package)		YG10K
YG10M-0-T4-G	puckage)		YG10M
YG10Y-0-T4-G			YG10Y





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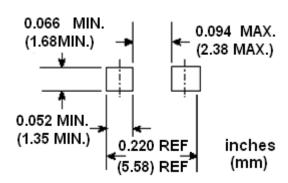
Maximum Ratings and Electrical Characteristics

(Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.)

Parameter	Symbol Type							Units	
Parameter	Symbol	YG10D	YG10G	YG10J	YG10K	YG10M	YG10Y	Units	
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	1000	1600	V	
Maximum RMS voltage	V _{RMS}	140	280	420	560	700	1120	V	
Maximum DC blocking voltage	V_R	200	400	600	800	1000	1600	V	
Maximum instantaneous forward voltage, IF=1.5A	VF	1.15						V	
Maximum average forward rectified current	I _F (AV)	1.5						A	
Peak forward surge current @8.3ms single half sine wave superimposed on rated load (JEDEC method)		30						A	
Maximum DC reverse current VR=VRRM,TA=25°C VR=VRRM,TA=100°C		1 10					μΑ		
Maximum reverse recovery time (Note 1)	trr	4				us			
Typical thermal reistance (Note 2)	RθJA RθJC	125 40					°C/W		
Non-Repetitive Peak Reverse Avalanche Energy at 25 °C, IAS=1A / L=10mH	Eas	20				mJ			
Storage temperature range	Tstg	-55 ~ +150						$^{\circ}\!\mathbb{C}$	
Operating junction temperature range	TJ	-55 ~ +150				$^{\circ}\!\mathbb{C}$			

Note: 1.Reverse recovery time conditions : IF=0.5A, IR=1A, IRR=0.25A

Recommended soldering footprint



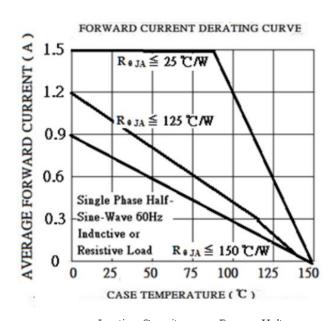
^{2.}P.C.B. mounted on 0.2"x0.2"(5.0mmx5.0mm) copper pad area.

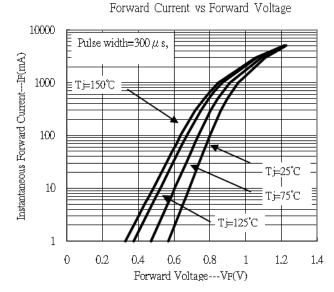


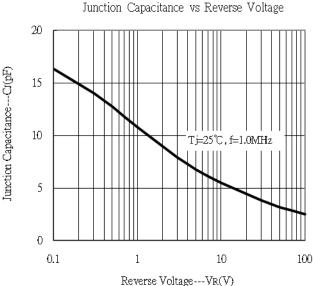
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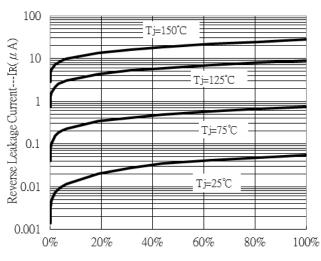
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Characteristic Curves









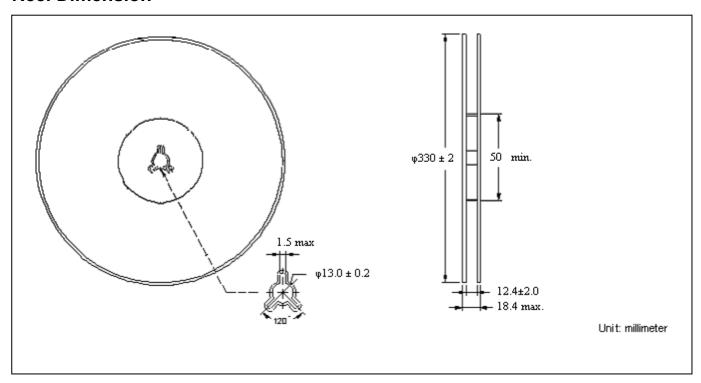
Reverse Leakage Current vs Reverse Voltage



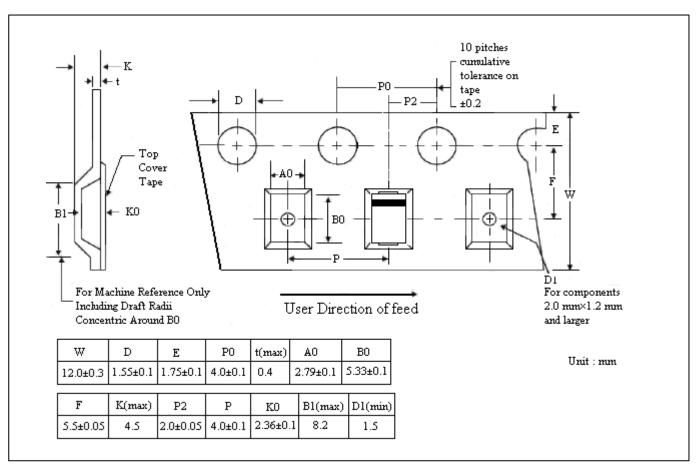
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Reel Dimension



Carrier Tape Dimension





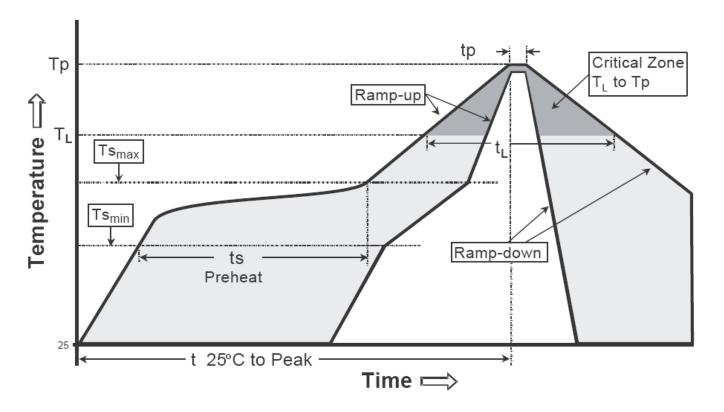
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Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly	
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.	
Preheat			
-Temperature Min(Ts min)	100°C	150°C	
-Temperature Max(Ts max)	150°C	200°C	
-Time(ts min to ts max)	60-120 seconds	60-180 seconds	
Time maintained above:			
-Temperature (T∟)	183°C	217°C	
- Time (t∟)	60-150 seconds	60-150 seconds	
Peak Temperature(T _P)	240 +0/-5 °C	260 +0/-5 °C	
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds	
Ramp down rate	6°C/second max.	6°C/second max.	
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.	

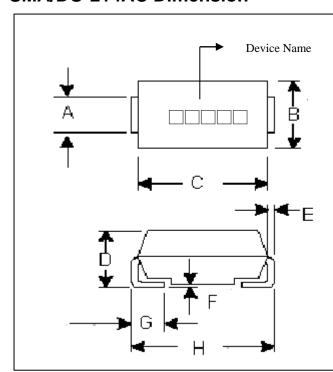
Note: All temperatures refer to topside of the package, measured on the package body surface.



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SMA/DO-214AC Dimension



Marking:							
Device	YG10D	YG10G	YG10J				
Code	YG10D	YG10G	YG10J				

Device	YG10K	YG10M	YG10Y
Code	YG10K	YG10M	YG10Y

SMA/DO-214AC Plastic Surface Mounted Package CYStek Package Code: SA

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
וווט	Min. Max. Min.	Max.	Min.	Max.		Min.	Max.		
Α	0.052	0.062	1.32	1.60	Е	0.006	0.012	0.15	0.31
В	0.098	0.114	2.50	2.90	F	0.002	0.008	0.05	0.20
С	0.154	0.181	3.90	4.60	G	0.030	0.060	0.76	1.52
D	0.067	0.098	1.70	2.50	Н	0.188	0.208	4.80	5.28

Notes: 1.Controlling dimension: millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead : Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class:UL94V-0.

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